NSN 5961-01-595-5176

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-595-5176 **Inclosure Material:** Ceramic **Overall Length:** 0.040 inches **Overall Width:** 0.020 inches **End Application:** Patriot, p/n 11481670 **Mounting Method:** Terminal **Semiconductor Material:** Zinc sulfide **Voltage Rating In Volts Per Characteristic:** 18.5 breakdown voltage, dc **Current Rating Per Characteristic:** 20.00 amperes peak point current **Product Name:** Semi-conductor device, diode-multilayer ceramic transient voltage supressor **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No